SINGLE-SUPPLY LOW POWER DUAL OPERATIONAL AMPLIFIER

■ GENERAL DESCRIPTION

The NJM2132 is a general purpose single supply low power dual operational amplifier.

The features of low operating current, wide and low operating voltage, high input inpedance, and single supply operation are suitable for battery operated items.

■ FEATURES

Operating Voltage

Low Operating Current

Slew Rate

Gain Bandwidth Product

Bipolar Technology

Package Outline

 $(+2.7V \sim +32V)$

(180 μ A typ. @V+=5V, each amplifier)

 $(2.1 \text{V}/ \mu \text{s typ.})$

(1.8MHz typ.)

DIP8, DMP8, SSOP8, SIP8

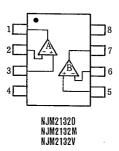
■ PACKAGE OUTLINE

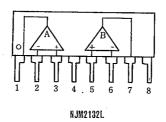




NJM2132M

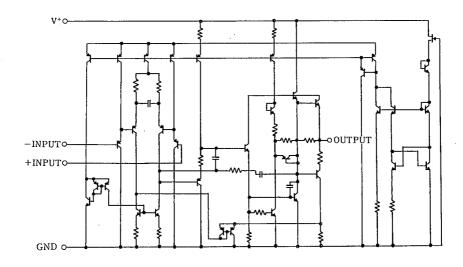
■ PIN CONFIGURATION





PIN FUNCTION 1. A OUTPUT 2. A -INPUT 3. A +INPUT 4. V-5. B +INPUT 6. B -INPUT 7. B OUTPUT 8. V+

■ EQUIVALENT CIRCUIT (1/2 Shown)



■ ABSOLUTE MAXIMUM RATINGS

(Ta=25℃)

PARAMETER	SYMBOL	RATINGS	UNIT	
Supply Voltage	V+	36		
Differential Input Voltage	· V _{ID}	±36	V	
Input Voltage	V _{IC}	-0.3~+36(note)	V	
Power Dissipation	P _D	(DIP-8) 500 (DMP-8) 300 (SSOP-8) 250 (SIP-8) 800	mW	
Operating Temperature Range	Topr	-40∼+85	°C	
Storage Temperature Range	T _{stg}	-50~+125	C	

(note) When the supply voltage is less than +36V, the absolute maximum input voltage is equal to the supply voltage.

■ ELECTRICAL CHARACTERISTICS

 $(V^+/V^-=\pm 15V, Ta=25^{\circ}C)$

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Operating Voltage	V+ :	Single Supply	+2.7		+32	V
Input Offset Voltage		R _s =0Ω	_	2.0	4.5	mV
	V _{io}	$V^{+}=+5V, V^{-}=0V, R_{S}=0\Omega$	_	2.5	5.0	
V _{IO} Drift	⊿ V _{io} /T	R _S =0 Ω	_	10	_	μV/°C
Input Offset Current	I _{IO}		_	5	20	nA
Input Bias Current	IB		_	20	100	пА
Large Signal Voltage Gain	Av	$R_L \ge 10 k \Omega$, $V_0 = \pm 10 V$. 94	114	_	dB
Input Common Mode Voltage Range	V _{ICM}		-15	-15~+13.5(MIN)		V
Common mode Rejection Ratio	CMR	$R_s \leq 10k\Omega$	80	90	_	dB
Supply Voltage Rejection Ratio	SVR	R _S =100 Ω	80	100	_	dB
Maximum Output Voltage Swing	V _{OM}	$R_L=10k\Omega$	±13.6	±14.2	_	V
	+V _{OM}	V+=+5V, V==0V	3.5	4.3	_	
	-V _{OM}	$R_L=10k\Omega$	_	0.05	0.15	
Operating Current		R _L =∞(all Amp.)		440	500	μА
	I _{CC}	V+=+5V, V==0V	_	360	500	
Output Source Current	I _{SOURCE}	$V_{IN}^+=IV$, $V_{IN}^-=0V$	3.0	5.0	-	mA
Output Sink Current	I _{SINK}	$V_{IN}^{+}=0V, V_{IN}^{-}=1V$	15	27	ı	mA
Input Resistance	R _{IN}		-	300	-	МΩ
Input Capacitance	Ci			0.8	_	pF
Close Loop Output Impedance	Zo	f=1.0MHz	-	100	_	Ω
Equivalent Input Noise Voltage	en	$R_S=100\Omega$, $f=1kHz$	_	32	-	nV/√Hz
Slew Rate	SR	$R_L=10k\Omega$		2.1	-	V/ μs
Gain Bandwidth Product	GB	f=100kHz		1.8	_	MHz
Power Bandwidth	DW/	$A_{V}=+1.0, R_{L}=10k\Omega$		35	_	kHz
	BWp	V _O =20V _{p-p} , THD=5%	-			
Phase Margin	,	R _L =10kΩ	-	60	-	deg.
	. фм	$R_L=10k\Omega$, $C_L=100_pF$	_	45	_	
Amplitude Margin		$R_L=10k\Omega$	_	15	_	dB
	A _m	$R_L=10k\Omega, C_L=100_pF$		5.0		
Total Harmonic Distortin	TIID	$A_{V}=+10, R_{L}=10k\Omega$		0.03		
	THD	$f=10kHz$, $2 \le V_0 \le 20V_{p-p}$		- 0.03 -		%
Channel Separation	CS	f=10kHz, Input Referrd	_	120	_	dB

MEMO

[CAUTION]
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